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Serial No.: 10/647,714

Conf. No.: 2476

Filing Date: 08/25/2003

Art Unit: 2818

Applicant: Khan et al.

Examiner: Le, Thao P.

Title: METAL OXIDE SEMICONDUCTOR
HETEROSTRUCTURE FIELD EFFECT
TRANSISTOR

Docket No.: SETI-0002DIV

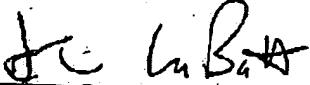
COMMISSIONER FOR PATENTS

DESTINATION PHONE NUMBER: 703-872-9306

Transmitted herewith is: Amendment in 11 pages

in the above identified application.

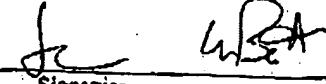
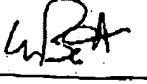
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DATE: May 25, 2004

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